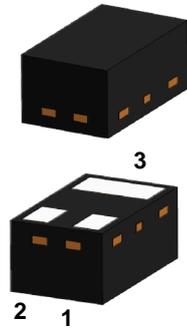


**Absolute Maximum Ratings** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Symbol          | Parameter                                       | Value       | Units              |
|-----------------|---|-------------|--------------------|
| $V_{CBO}$       | Collector-Base Voltage                          | -40         | V                  |
| $V_{CEO}$       | Collector-Emitter Voltage                       | -40         | V                  |
| $V_{EBO}$       | Emitter-Base Voltage                            | -5          | V                  |
| $I_C$           | Collector Current                               | -200        | mA                 |
| $P_D$           | Power Dissipation<br>(FR-4 Board – minimum pad) | 200         | mW                 |
| $R_{\theta JA}$ | Thermal Resistance from Junction to Ambient     | 600         | $^\circ\text{C/W}$ |
| $T_J$ $T_{STG}$ | Junction & Storage Temperature Range            | -55 to +150 | $^\circ\text{C}$   |

These ratings are limiting values above which the serviceability of the device may be impaired.

**Green Product**

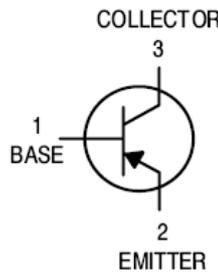


SOT-883 (DFN1006-3)

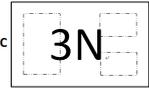
**Specification Features:**

- § DFN1006-3
- § Simplifies Circuit Design
- § RoHS Compliant
- § Green EMC
- § Matte Tin(Sn) Lead Finish
- § Weight: approx. 0.001g

**Electrical Symbol:**



**Device Marking Code:**

| Device Type      | Marking   | Shipping    |
|------------------|---|-------------|
| MMBT3906FZ-7B-CN |  | 10,000/Reel |

**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

**Off Characteristics**

| Symbol        | Parameter                                       | Test Condition                                 | Limits |      | Unit  |
|---------------|---|--|--------|------|-------|
|               |   |  | Min    | Max  |       |
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage<br>(Note 1) | $I_C = -1\text{mA}$ , $I_B = 0\text{A}$        | -40    | -    | Volts |
| $V_{(BR)CBO}$ | Collector-Base Breakdown Voltage                | $I_C = -10\mu\text{A}$ , $I_E = 0\text{A}$     | -40    | -    | Volts |
| $V_{(BR)EBO}$ | Emitter-Base Breakdown Voltage                  | $I_E = -10\mu\text{A}$ , $I_B = 0\text{A}$     | -5     | -    | Volts |
| $I_{CEX}$     | Collector Cutoff Current                        | $V_{CE} = -30\text{V}$ , $V_{EB} = -3\text{V}$ | -      | -50  | nA    |
| $I_{EBO}$     | Emitter Cutoff Current                          | $V_{EB} = -5\text{V}$ , $I_C = 0\text{A}$      | -      | -100 | nA    |

Note 1: Pulse Test. Pulse width <300us, Duty cycle < 2.0%.

On Characteristics (Note 1)

| Symbol        | Parameter                            | Test Condition               | Limits |       | Unit  |
|---------------|--------------------------------------|------------------------------|--------|-------|-------|
|               |                                      |                              | Min    | Max   |       |
| $H_{FE}$      | DC Current Gain                      | $I_C = -0.1mA, V_{CE} = -1V$ | 60     | -     | -     |
|               |                                      | $I_C = -1.0mA, V_{CE} = -1V$ | 80     | -     |       |
|               |                                      | $I_C = -10mA, V_{CE} = -1V$  | 100    | 300   |       |
|               |                                      | $I_C = -50mA, V_{CE} = -1V$  | 60     | -     |       |
|               |                                      | $I_C = -100mA, V_{CE} = -1V$ | 30     | -     |       |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = -10mA, I_B = -1mA$    | -      | -0.25 | Volts |
|               |                                      | $I_C = -50mA, I_B = -5mA$    | -      | -0.4  |       |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage      | $I_C = -10mA, I_B = -1mA$    | -0.65  | -0.85 | Volts |
|               |                                      | $I_C = -50mA, I_B = -5mA$    | -      | -0.95 |       |

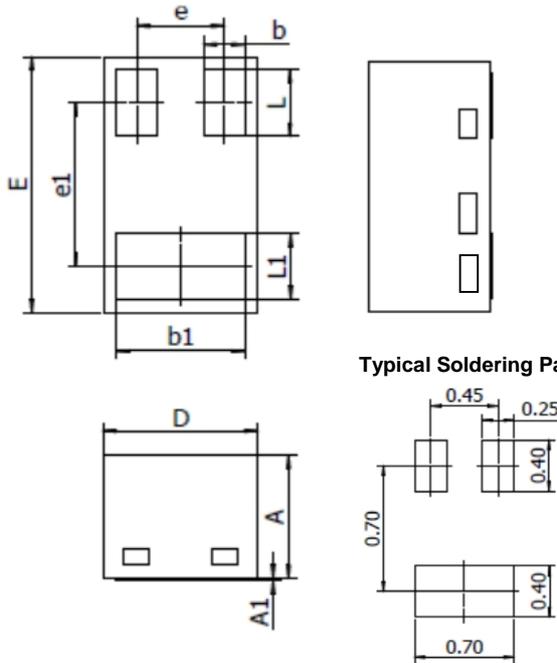
Small-signal Characteristics

| Symbol    | Parameter                      | Test Condition  | Limits |     | Unit             |
|-----------|--------------------------------|---|--------|-----|------------------|
|           |                                |   | Min    | Max |                  |
| $f_T$     | Current-Gain-Bandwidth Product | $I_C = -10mA, V_{CE} = -20V, f = 100MHz$                          | 250    | -   | MHz              |
| $C_{obo}$ | Output Capacitance             | $V_{CB} = -5V, I_E = 0A, f = 1.0MHz$                              | -      | 4.5 | pF               |
| $C_{ibo}$ | Input Capacitance              | $V_{BE} = -0.5V, I_C = 0A, f = 1.0MHz$                            | -      | 10  | pF               |
| $h_{ie}$  | Input Impedance                | $V_{CE} = -10V, I_C = -1mA, f = 1.0kHz$                           | 2      | 12  | pF               |
| $h_{re}$  | Voltage Feedback Ratio         | $V_{CE} = -10V, I_C = -1mA, f = 1.0kHz$                           | 0.1    | 10  | $\times 10^{-4}$ |
| $h_{fe}$  | Small-signal Current Gain      | $V_{CE} = -10V, I_C = -1mA, f = 1.0kHz$                           | 100    | 400 | -                |
| $h_{oe}$  | Output Admittance              | $V_{CE} = -10V, I_C = -1mA, f = 1.0kHz$                           | 3      | 60  | $\theta$ mhos    |
| NF        | Noise Figure                   | $V_{CE} = -5V, I_C = -100\mu A$<br>$R_s = 1.0k\Omega, f = 1.0kHz$ |        | 4   | dB               |

Switching Characteristics

| Symbol | Parameter    | Test Condition                  | Limits |     | Unit |
|--------|--------------|---------------------------------|--------|-----|------|
|        |              |                                 | Min    | Max |      |
| $t_d$  | Delay Time   | $V_{CC} = -3V, V_{BE} = -0.5V,$ | -      | 35  | nS   |
| $t_r$  | Rise Time    | $I_C = -10mA, I_{B1} = -1mA$    | -      | 35  |      |
| $t_s$  | Storage Time | $V_{CC} = -3V, I_C = -10mA,$    | -      | 225 | nS   |
| $t_f$  | Fall Time    | $I_{B1} = I_{B2} = -1mA$        | -      | 75  |      |

SOT-883 Package Outline



| DIM | MILLIMETERS |      | INCHES     |       |
|-----|-------------|------|------------|-------|
|     | MIN         | MAX  | MIN        | MAX   |
| A   | 0.46        | 0.50 | 0.018      | 0.020 |
| A1  | ---         | 0.03 | ---        | 0.001 |
| D   | 0.55        | 0.65 | 0.022      | 0.026 |
| E   | 0.95        | 1.05 | 0.037      | 0.041 |
| b   | 0.12        | 0.22 | 0.005      | 0.008 |
| b1  | 0.45        | 0.55 | 0.018      | 0.022 |
| L   | 0.22        | 0.32 | 0.008      | 0.013 |
| L1  | 0.22        | 0.32 | 0.008      | 0.013 |
| e   | Typ. 0.34   |      | Typ. 0.013 |       |
| e1  | Typ. 0.65   |      | Typ. 0.026 |       |

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